NSN 5962-01-069-9685



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-069-9685 **Body Length:** 0.870 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.120 inches and 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Trainer, simulator, electronic warfare, type an/alq-t4 **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and 3-state output and w/enable and w/buffered output and w/decoded output and bipolar **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 15786-305302 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Yes - demil/mli

Demilitarization:

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